



**ELECTRONICS, INC.**  
 44 FARRAND STREET  
 BLOOMFIELD, NJ 07003  
 (973) 748-5089

## NTE234 Silicon PNP Transistor Low Noise, High Gain Amplifier

**Description:**

The NTE234 is a silicon PNP transistor in a TO92 type package designed especially for low noise preamplifier and small signal industrial amplifier applications. This device features low collector saturation voltage, tight beta control, and excellent low noise characteristics.

**Features:**

- Low Noise
- High DC Current Gain
- High Breakdown Voltage
- Low Pulse Noise

**Absolute Maximum Ratings:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Collector–Emitter Voltage, $V_{CEO}$ .....	120V
Collector–Base Voltage, $V_{CBO}$ .....	120V
Emitter–Base Voltage, $V_{EBO}$ .....	5V
Steady State Collector Current, $I_C$ .....	100mA
Emitter Current, $I_E$ .....	100mA
Collector Power Dissipation, $P_C$ .....	300mW
Operating Junction Temperature Range, $T_J$ .....	$-55^\circ$ to $+125^\circ\text{C}$
Storage Temperature Range, $T_{stg}$ .....	$-55^\circ$ to $+125^\circ\text{C}$

**Electrical Characteristics:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cutoff Current	$I_{CBO}$	$V_{CB} = 120\text{V}, I_E = 0$	–	–	100	nA
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = 5\text{V}, I_C = 0$	–	–	100	nA
Breakdown Voltage Collector–to–Emitter	$V_{(BR)CEO}$	$I_C = 1\text{mA}, I_B = 0$	120	–	–	V
DC Current Gain	$h_{FE}$	$V_{CE} = 6\text{V}, I_C = 2\text{mA}$	350	–	700	

**Electrical Characteristics (Cont'd):** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Saturation Voltage Collector-to-Emitter	$V_{CE(sat)}$	$I_C = 10\text{mA}, I_B = 1\text{mA}$	-	-	0.3	V
Base-to-Emitter Voltage	$V_{BE}$	$V_{CE} = 6\text{V}, I_C = 2\text{mA}$	-	0.65	-	V
Transition Frequency	$f_T$	$V_{CE} = 6\text{V}, I_C = 1\text{mA}$	-	100	-	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB} = 10\text{V}, I_E = 0, f = 1\text{MHz}$	-	4	-	pF
Noise Figure	NF	$V_{CE} = 6\text{V}, I_C = 100\mu\text{A},$ $f = 10\text{Hz}, R_g = 10\text{k}\Omega$	-	-	6	dB
		$V_{CE} = 6\text{V}, I_C = 100\mu\text{A},$ $f = 1\text{Hz}, R_g = 10\text{k}\Omega$	-	-	2	
		$V_{CE} = 6\text{V}, I_C = 100\mu\text{A},$ $f = 1\text{Hz}, R_g = 100\text{k}\Omega$	-	3	-	

